

PTO/SB/21 (08-00)

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Total Number of	of Pages in	This Submis	ssion	

Application Number	08/818,884
Filing Date	March 17, 1997
First Named Inventor	Shunpei YAMAZAKI et al.
Group Art Unit	2871
Examiner Name	Dung T. Nguyen
Attorney Docket Number	0756-1653

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	; E	NCLOSURES (check all that apply	у)			
Fee Transmittal Form Fee Attached Amendment / Reply After Final Affidavits/declaration(s) Extension of Time Request Express Abandonment Rec Information Disclosure Stat Certified Copy of Priority Document(s) Response to Missing Parts Incomplete Application Response to Missing P under 37 CFR 1.52 or	quest tement	Assignment Papers (for an Application) Drawing(s) Declaration and Power of Attorney Licensing-related Papers Petition Petition to Convert to a Provisional Application Power of Attorney, Revocation Change of Correspondence Address Terminal Disclaimer Request for Refund CD, Number of CD(s) Remarks The Commissioner is	After Allowance Communication to Group Appeal Communication to Board of Appeals and Interferences Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) Proprietary Information Status Letter Other Enclosures 1. Correction to Previously Submitted IDS and PTO 1449 Form 2. 3. 4. 5. 6.			
	SIGNATUR	RE OF APPLICANT, ATTORNEY, O	DR AGENT			
Firm or Individual name Signature	Eric J. Rol Robinson PMB 955 21010 Sou	pinson, Reg. No. 38,285 Intellectual Property Law Office, uthbank Street Falls, VA 20165				
Date	2-27-	-0 5				
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Attorney Docket No. 0756-1653



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:)	Group Art Unit: 2871
Shunpei YAMAZAKI et al.)	Examiner: D. Nguyen
Serial No. 08/818,884)	CERTIFICATE OF MAILING I hereby certify that this correspondence is
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CORRECTION TO PREVIOUSLY SUBMITTED INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

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It has come to applicant's attention that several Information Disclosure Statements previously submitted included inadvertent typographical errors or incomplete information.

Specifically, the Information Disclosure Statement filed February 1, 2000, included the following inaccuracy:

1) U.S. Patent 5,616,944 was incorrectly listed with the inventor as Miutani et al. The correct inventor should be Mizutani et al.

The Information Disclosure Statement filed October 24, 2000, including the following inaccuracies:

- 1) U.S. Patent No. 5,851,440 was incorrectly listed with an issue date of 12/01/1998. The correct issue date is 12/22/1998.
- 2) U.S. Patent No. 4,743,567 was incorrectly listed with the inventor as Pandy et al. The correct inventor should be Pandya et al.
- 3) U.S. Patent No. 5,514,879 was incorrectly listed with an issue date of 05/01/1996. The correct issue date is 05/07/1996.

4) The Hatalis et al. article was incorrectly listed with the wrong page numbers. The correct page numbers are 361-364.

The above inaccuracies are corrected on the 1449 Form attached hereto. The Examiner is requested to initial the attached PTO Form 1449 evidencing consideration of the above references and line through these references on the previously submitted Information Disclosure Statements to ensure that the correct information is printed correctly on any issued patent.

Respectfully submitted,

Eric J. Robinson

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Reg. No. 38,285

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Approved for use through 10/31/2002. OMB 0651-0031

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Substitute for form 1449A/PTO				Complete if Known		
INFORMATION DISCLOSURE				Application Number	08/818,884	
STATEMENT BY APPLICANT				Filing Date	March 17, 1997	
				First Named Inventor	Shunpei YAMAZAKI et al.	
(use as many sheets as necessary)		Group Art Unit	2871			
				Examiner Name	D. Nguyen	
Sheet	l	of	1	Attorney Docket Number	0756-1653	

U.S. PATENT DOCUMENTS								
Examiner Cite Initials No.1	U.S. Patent Document		Name of Patentee or Applicant of Cited	Date of Publication of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
		Number Kind (if kno		Document	MM-DD-YYYY			
		5,616,944		Mizutani et al.	04/01/1997			
		5,851,440		Tanaka et al.	12/22/1998			
		4,743,567		Pandya et al.	05/10/1988			
		5,514,879		Yamazaki	05/07/1996			
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				<u>FOREIGN PATENT DOC</u>	UMENIS			
Cite No.	Foreign Patent Document Kind Code ⁵ Office ³ Number ⁴ (if known)			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶	
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	·	O	THER PRIO	R ART – NON PATENT LITI	ERATURE DOCUMENTS			
Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published. M.K. HATALIS et al., High-Performance Thin-Film Transistors in Low-Temperature Crystallized LPCVD Amorphous Silicon Films, IEEE Electron Device Letters. Vol. 1, EDL8, No. 8, August, 1987, Pages 361-364.					T ²		
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	No.¹	Office ³ Office ³ Cite No. ¹ M.K. Cryste	Office ³ Number ⁴ Office ³ Number ⁴ OT Cite Include r item (bot) M.K. HATALI Crystallized LF	Office ³ Number ⁴ Kind Code ³ (if known) OTHER PRIOR Cite No. ¹ Include name of the au item (book, magazine, justice of the control of	No. 1 Office 3 Number 4 (if known) Name of Patentee or Applicant of Cited Document OTHER PRIOR ART – NON PATENT LITI Cite No. 1 Include name of the author (in CAPITAL LETTERS), item (book, magazine, journal, serial, symposium, cata publisher, city and/or cour M.K. HATALIS et al., High-Performance Third Crystallized LPCVD Amorphous Silicon Films,	Name of Patentee or Applicant of Cited Document Name of Patentee or Applicant of Cited Document	Name of Patentee or Applicant of Cited Document MM-DD-YYYY Office ³ Number ⁴ (if known) Name of Patentee or Applicant of Cited Document MM-DD-YYYY Office ³ Number ⁴ (if known) OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS Cite No. ¹ Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published. M.K. HATALIS et al., High-Performance Thin-Film Transistors in Low-Temperature Crystallized LPCVD Amorphous Silicon Films, IEEE Electron Device Letters. Vol. 1,	

Examiner	Date	
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.